

## DUAL OPERATIONAL AMPLIFIER

### ■ GENERAL DESCRIPTION

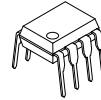
The NJM4558/4559 integrated circuit is a dual high-gain operational amplifier internally compensated and constructed on a single silicon chip using an advanced epitaxial process.

Combining the features of the NJM741 with the close parameter matching and tracking of a dual device on a monolithic chip results in unique performance characteristics. Excellent channel separation allow the use of the dual device in single NJM741 operational amplifier applications providing density. It is especially well suited for applications in differential-in, differential-out as well as in potentiometric amplifiers and where gain and phase matched channels are mandatory.

### ■ FEATURES

- Operating Voltage (  $\pm 4V \sim \pm 18V$  )
- High Voltage Gain ( 100dB typ. )
- High Input Resistance (  $5M\Omega$  typ. )
- Bipolar Technology
- Package Outline  
 DIP8, DMP8, SIP8  
 EMP8 (only NJM4558),  
 SSOP8 (only NJM4558)

### ■ PACKAGE OUTLINE



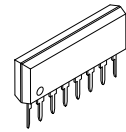
NJM4558D  
NJM4559D



NJM4558M  
NJM4559M



NJM4558V

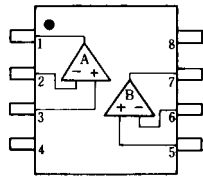


NJM4558L  
NJM4559L

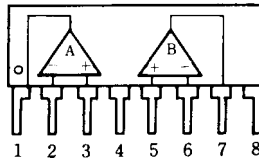


NJM4558E

### ■ PIN CONFIGURATION



NJM4558D, NJM4558M, NJM4558V  
NJM4559D, NJM4559M, NJM4558E

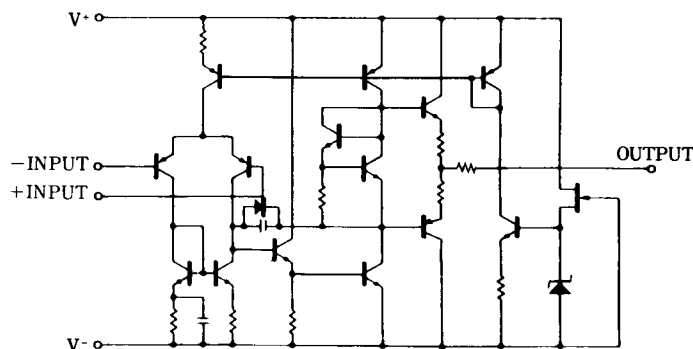


NJM4558L  
NJM4559L

### PIN FUNCTION

- 1.A OUTPUT
- 2.A -INPUT
- 3.A +INPUT
- 4.V<sup>-</sup>
- 5.B +INPUT
- 6.B -INPUT
- 7.B OUTPUT
- 8.V<sup>+</sup>

### ■ EQUIVALENT CIRCUIT ( 1/2 Shown )



# NJM4558/4559

## ■ ABSOLUTE MAXIMUM RATINGS

( Ta=25°C )

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	$V^+ / V^-$	± 18	V
Differential Input Voltage	$V_{ID}$	± 30	V
Input Voltage	$V_{IC}$	± 15 ( note )	V
Power Dissipation	$P_D$	( DIP8 ) 500 ( DMP8 ) 300 ( EMP8 ) 300 ( SSOP8 ) 250 ( SIP8 ) 800	mW
Operating Temperature Range	$T_{opr}$	-40~+85	°C
Storage Temperature Range	$T_{stg}$	-40~+125	°C

( note ) For supply voltage less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

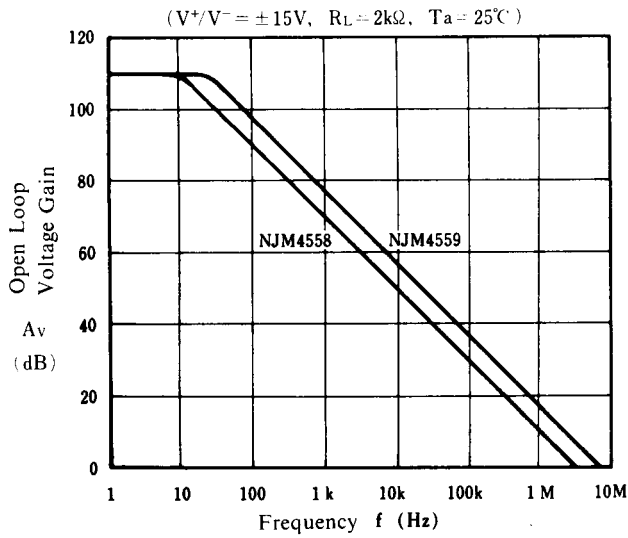
## ■ ELECTRICAL CHARACTERISTICS

(  $V^+ / V^- = \pm 15V, T_a = 25^\circ C$  )

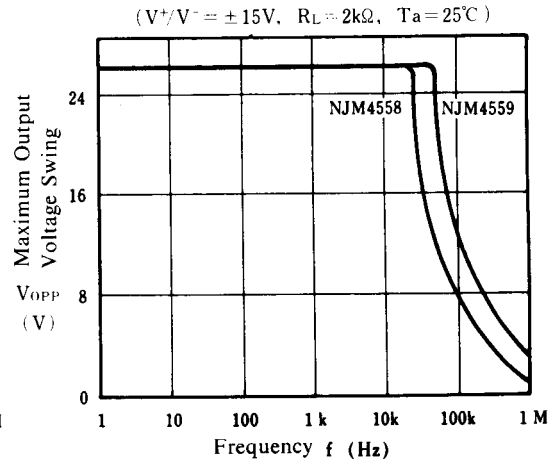
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	$V_{IO}$	$R_S \leq 10k\Omega$	-	0.5	6	mV
Input Offset Current	$I_{IO}$		-	5	200	nA
Input Bias Current	$I_B$		-	25	500	nA
Input Resistance	$R_{IN}$		0.3	5	-	MΩ
Large Signal Voltage Gain	$A_V$	$R_L \geq 2k\Omega, V_O = \pm 10V$	86	100	-	dB
Maximum Output Voltage Swing 1	$V_{OM1}$	$R_L \geq 10k\Omega$	± 12	± 14	-	V
Maximum Output Voltage Swing 2	$V_{OM2}$	$R_L \geq 2k\Omega$	± 10	± 13	-	V
Input Common Mode Voltage Range	$V_{ICM}$		± 12	14	-	V
Common Mode Rejection Ratio	CMR	$R_S \leq 10k\Omega$	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10k\Omega$	76.5	90	-	dB
Operating Current	$I_{CC}$		-	3.5	5.7	mA
Slew Rate						
	NJM4558	SR	-	1	-	V/μs
	NJM4559	SR	-	2	-	V/μs
Equivalent Input Noise Voltage	$V_{NI}$	RIAA, $R_S = 2.2k\Omega, 30kHz$ LPF	-	1.4	-	μVrms
Gain Bandwidth Product	GB					
	NJM4558			3		MHz
	NJM4559			6		MHz

## ■ TYPICAL CHARACTERISTICS

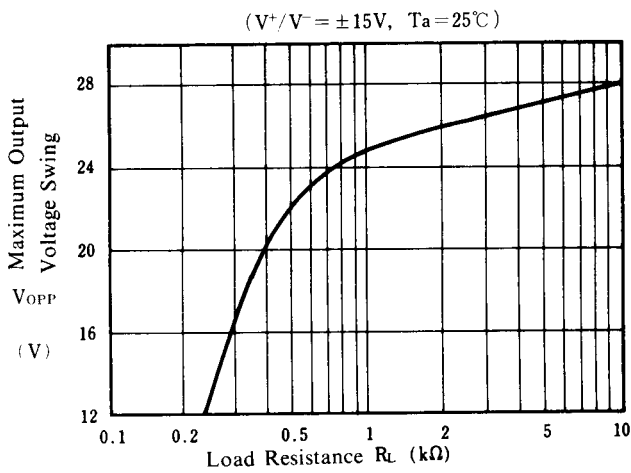
**Open Loop Voltage Gain vs. Frequency**



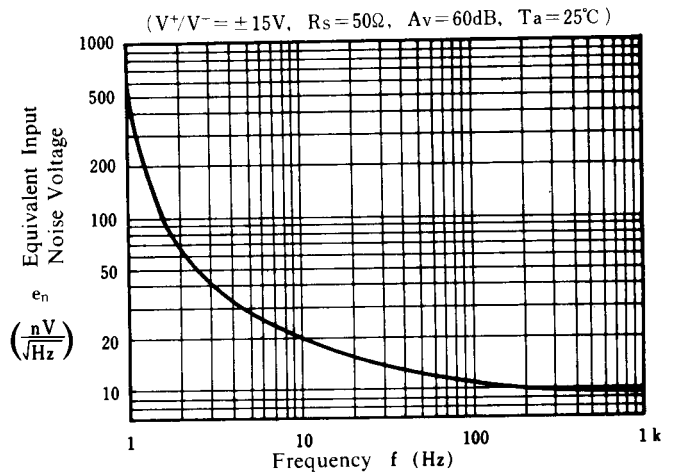
**Maximum Output Voltage Swing vs. Frequency**



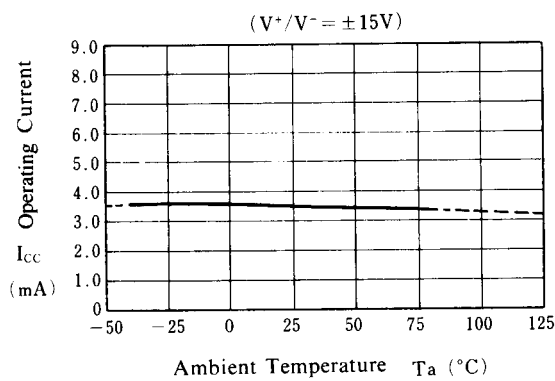
**Maximum Output Voltage Swing vs. Load Resistance**



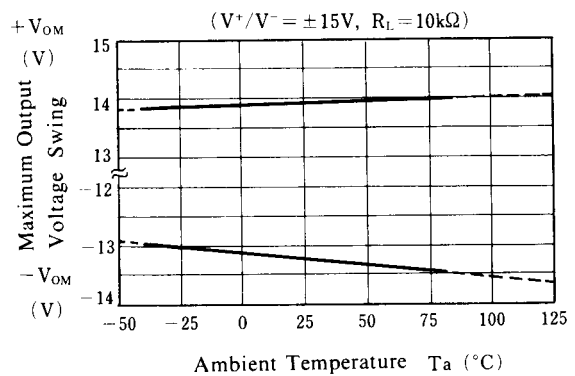
**Equivalent Input Noise Voltage vs. Frequency**



**Operating Current vs. Temperature**

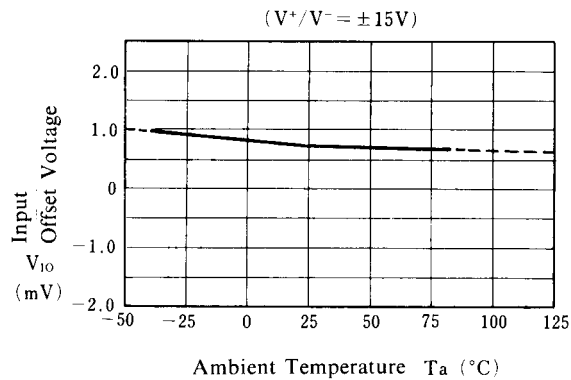


**Maximum Output Voltage Swing vs. Temperature**

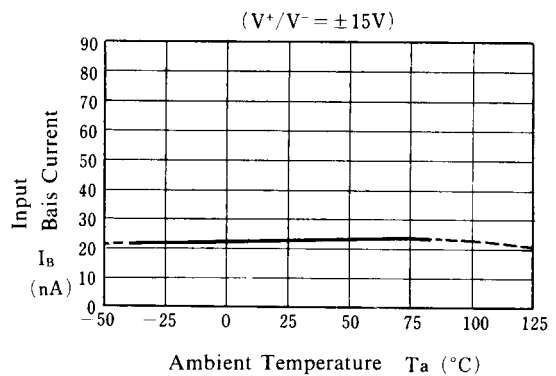


## ■ TYPICAL CHARACTERISTICS

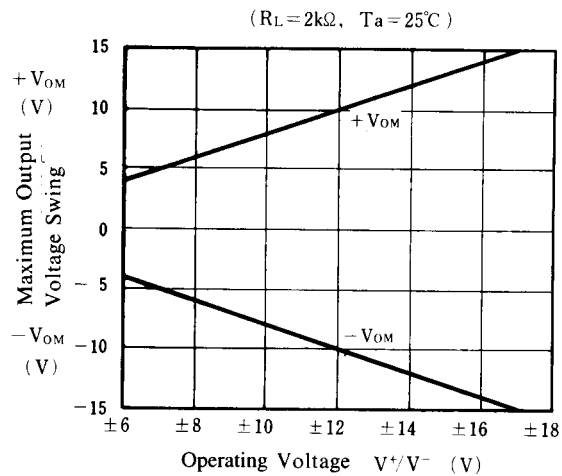
**Input Offset Voltage vs. Temperature**



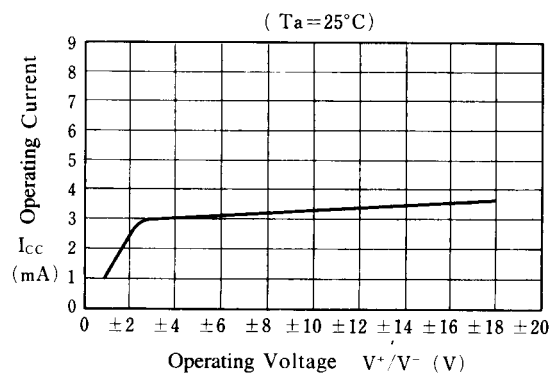
**Input Bias Current vs. Temperature**



**Maximum Output Voltage Swing vs. Operating Voltage**



**Operating Current vs. Operating Voltage**



**[CAUTION]**

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